

Date: - 07 August 2012

Data Sheet Issue:- 2

Rectifier Diode Types W2058LC100 to W2058LC140

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	1000-1400	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	1100-1500	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, T _{sink} =55°C, (note 2)	2058	Α
$I_{F(AV)M}$	Maximum average forward current. T _{sink} =100°C, (note 2)	1508	Α
$I_{F(AV)M}$	Maximum average forward current. T _{sink} =100°C, (note 3)	924	Α
I _{F(RMS)M}	Nominal RMS forward current, T _{sink} =25°C, (note 2)	3726	Α
I _{F(d.c.)}	D.C. forward current, T _{sink} =25°C, (note 4)	3225	Α
I _{FSM}	Peak non-repetitive surge t _p =10ms, V _m =60%V _{RRM} , (note 5)	19.5	kA
I _{FSM2}	Peak non-repetitive surge t _p =10ms, V _m ≤10V, (note 5)	21.5	kA
l ² t	I ² t capacity for fusing t _p =10ms, V _m =60%V _{RRM} , (note 5)	1.9×10 ⁶	A ² s
l ² t	I²t capacity for fusing t _p =10ms, V _{rm} ≤10V, (note 5)	2.3×10 ⁶	A ² s
T _{j op}	Operating temperature range	-40 to +175	°C
T _{stg}	Storage temperature range	-40 to +200	°C

Notes:

- 1) De-rating factor of 0.13% per °C is applicable for T_i below 25°C.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Single side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, 175°C T_i initial.



Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V_{FM}	Maximum peak forward voltage	-	-	1.63	I _{TM} =4400A	V
V_{FM}	Maximum peak forward voltage	-	-	1.8	I _{TM} =6175A	V
V_{T0}	Threshold voltage	-	-	0.79		V
r _T	Slope resistance	-	-	0.192		mΩ
I _{RRM}	Peak reverse current	-	-	30	Rated V _{RRM}	mA
I _{RRM}	Peak reverse current	-	-	30	Rated V _{RRM} , T _j =25°C	mA
Q _{rr}	Recovered charge	-	850	-		μC
Q_{ra}	Recovered charge, 50% Chord	-	600	850	I _{TM} =1000A, t _p =1000μs, di/dt=10A/μs,	μC
I _{rr}	Reverse recovery current	-	100	-	V _r =50V	Α
t _{rr}	Reverse recovery time	-	12	-		μs
0	The second secon	-	-	0.033	Double side cooled	K/W
R_{thJK}	Thermal resistance, junction to heatsink	-	-	0.066	Single side cooled	K/W
F	Mounting force	10	-	20		kN
W_t	Weight	-	340	-		g

Notes:-

¹⁾ Unless otherwise indicated T_j =175°C.



Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V _{DRM} V _{DSM} V _{RRM} V	V _{RSM} V	V _D V _R DC V
10	1000	1100	700
12	1200	1300	810
14	1400	1500	930

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{{V_{T0}}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T} \qquad \text{and:} \qquad W_{AV} = \frac{\Delta T}{R_{th}} \\ \Delta T = T_{j \max} - T_K$$

Where V_{T0} =0.79V, r_T =0.192m Ω ,

 R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance					
Conduction Angle	6 Phase (60°)	3 Phase (120°)	½ Wave (180°)	d.c.	
Square wave Double Side Cooled	0.0455	0.0393	0.0362	0.0319	
Square wave Single Side Cooled	0.0753	0.0711	0.0687	0.0646	
Sine wave Double Side Cooled	0.0397	0.0350	0.0313		
Sine wave Single Side Cooled	0.0699	0.0677	0.0653		

Form Factors						
Conduction Angle 6 Phase (60°) 3 Phase (120°) ½ Wave (180°) d.c				d.c.		
Square wave	2.449	1.732	1.414	1		
Sine wave	2.778	1.879	1.57			



5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F, on page 6 is represented in two ways;

- (i) the well established V_{T0} and r_T tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	175°C Coefficients
Α	1.09345181	0.890075253
В	0.03122052	0.02367562
С	4.872×10 ⁻⁵	5.14774×10 ⁻⁵
D	1.8884×10 ⁻³	4.745804×10 ⁻³



5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}}\right)$$

Where p = 1 to n, n is the number of terms in the series and:

t = Duration of heating pulse in seconds.

r, = Thermal resistance at time t.

 r_p = Amplitude of p_{th} term.

 τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

D.C. Single Side Cooled					
Term	Term 1 2 3 4 5				
rp	0.04013	6.3388×10 ⁻³	0.011408	6.0275×10 ⁻³	7.2098×10 ⁻⁴
$ au_{\mathcal{P}}$	4.07311	2.15774	0.19931	9.0689×10 ⁻³	4.66345×10 ⁻⁴

D.C. Double Side Cooled						
Term	n 1 2 3 4					
r_p	0.017719	4.2406×10 ⁻³	6.9638×10 ⁻³	3.04366×10 ⁻³		
$ au_{p}$	0.708578	0.1435833	0.036152	2.1308×10 ⁻³		

6.0 Reverse recovery ratings

(i) Q_{ra} is based on 50% I_{rm} chord as shown in Fig. 1

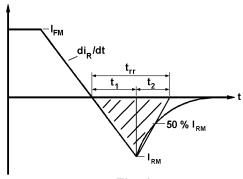


Fig. 1

$$Q_{rr} = \int_{0}^{150\,\mu s} i_{rr}.dt$$

(iii)
$$K Factor = \frac{t_1}{t_2}$$



Curves

Figure 1 - Forward characteristics of Limit device

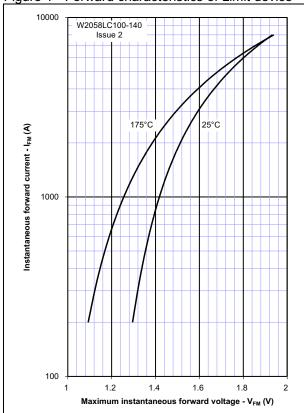


Figure 2 - Transient thermal impedance

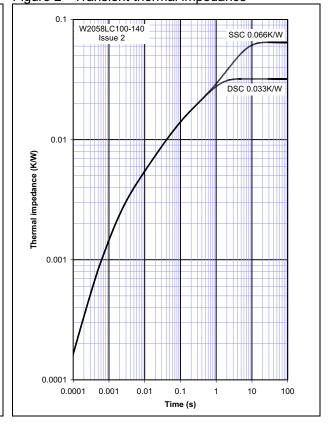


Figure 3 - Maximum surge Rating

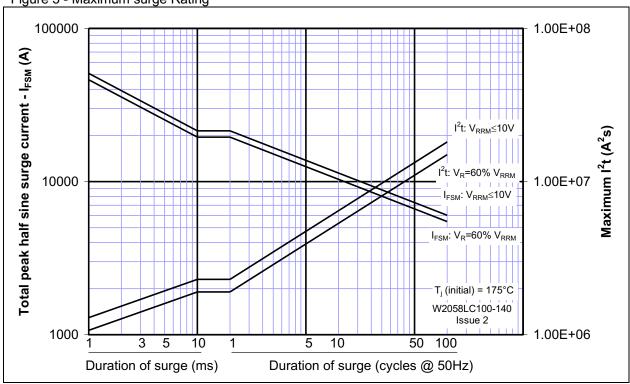




Figure 4 - Total recovered charge, Q_{rr}

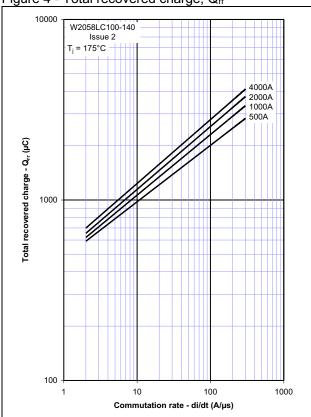
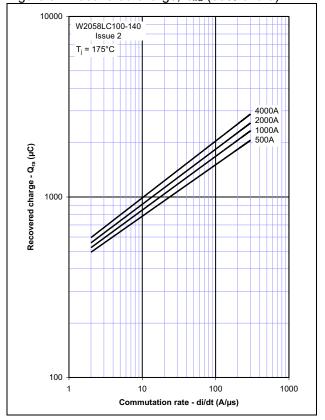


Figure 5 - Recovered charge, Q_{ra} (50% chord)



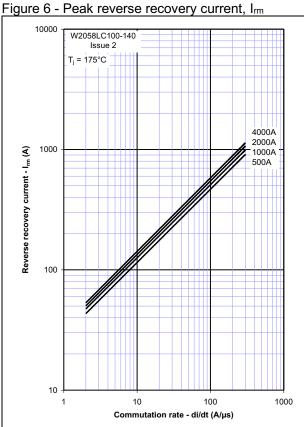


Figure 7 - Maximum recovery time, t_{rr} (50% chord)

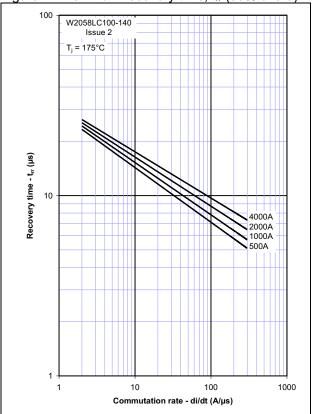




Figure 8 – Forward current vs. Power dissipation – Double Side Cooled

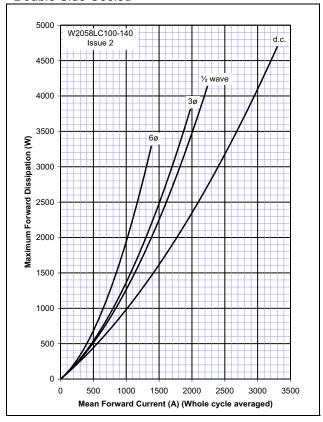


Figure 10 – Forward current vs. Power dissipation – Single Side Cooled

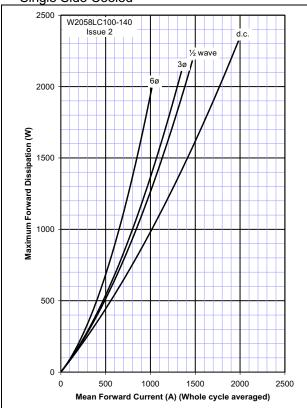


Figure 9 – Forward current vs. Heatsink temperature - Double Side Cooled

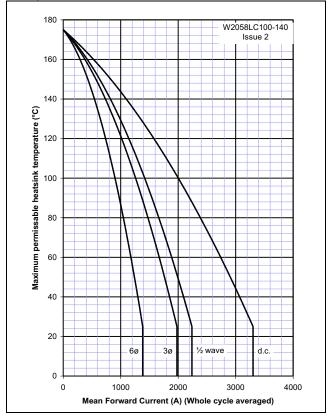
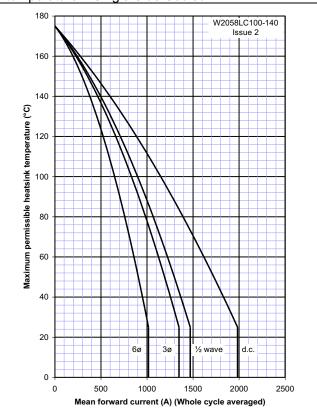
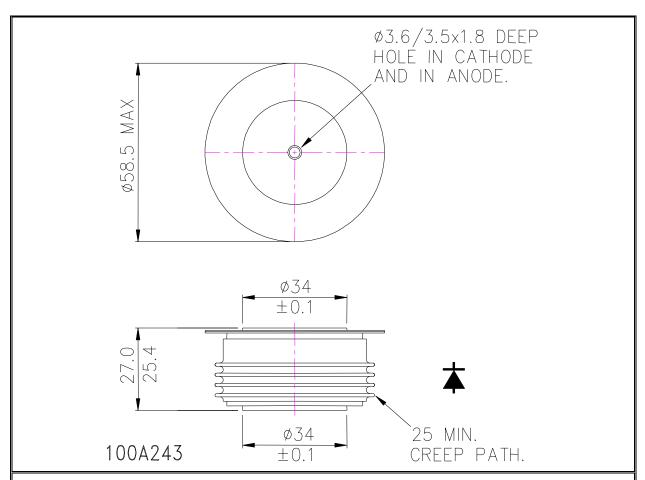


Figure 11 – Forward current vs. Heatsink temperature – Single Side Cooled





Outline Drawing & Ordering Information



ORDERING INFORMATION

(Please quote 10 digit code as below)

		(* 4	
W2058	LC	**	0
Fixed Type Code	Fixed outline code	Voltage code V _{DRM} /100 10-14	Fixed turn-off time code

Order code: W2058LC140 – 1400V V_{DRM}, V_{RRM}, 27mm clamp height capsule.

IXYS Semiconductor GmbH

Edisonstraße 15 D-68623 Lampertheim Tel: +49 6206 503-0 Fax: +49 6206 503-627 E-mail: marcom@ixys.de



IXYS UK Westcode Ltd

Langley Park Way, Langley Park, Chippenham, Wiltshire, SN15 1GE. Tel: +44 (0)1249 444524 Fax: +44 (0)1249 659448 E-mail: sales@ixysuk.com

IXYS Corporation

1590 Buckeye Drive Milpitas CA 95035-7418 Tel: +1 (408) 457 9000 Fax: +1 (408) 496 0670 E-mail: sales@ixys.net

www.ixysuk.com

www.ixys.com

IXYS Long Beach

IXYS Long Beach, Inc 2500 Mira Mar Ave, Long Beach CĂ 90815

Tel: +1 (562) 296 6584

Fax: +1 (562) 296 6585 E-mail: service@ixyslongbeach.com

© IXYS UK Westcode Ltd.

The information contained herein is confidential and is protected by Copyright. The information may not be used or disclosed except with the written permission of and in the manner permitted by the proprietors IXYS UK Westcode Ltd. In the interest of product improvement, IXYS UK Westcode Ltd reserves the right to change specifications at any time

without prior notice.

Devices with a suffix code (2-letter or letter/digit/letter combination) added to their generic code are not necessarily subject to the conditions and limits contained in this report.

